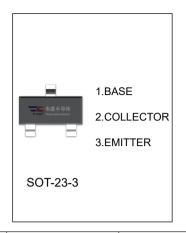


2SA1037 TRANSISTOR (PNP)

FEATURES

- Excellent h_{FE} linearity.
- Complments the 2SC2412



MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-60	V
V _{CEO}	Collector-Emitter Voltage	-50	V
V _{EBO}	Emitter-Base Voltage	-6	V
Ic	Collector Current -Continuous	-150	mA
Pc	Collector Power Dissipation	200	mW
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55-150	℃

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-50μA,I _E =0	-60			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-1mA,I _B =0	-50			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-50μA,I _C =0	-6			V
Collector cut-off current	I _{CBO}	V _{CB} =-60V,I _E =0			-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-6V,I _C =0			-0.1	μΑ
DC current gain	h _{FE}	V _{CE} =-6V,I _C =-1mA	120		560	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-50mA,I _B =-5mA			-0.5	V
Transition frequency	f _T	V _{CE} =-12V,I _C =-2mA,f=30MHz		140		MHz
Collector output capacitance	C _{ob}	V _{CB} =-12V,I _E =0,f=1MHz		4.0	5.0	pF

CLASSIFICATION OF hFE

Rank	Q	R	s
Range	120 - 270	180 - 390	270 - 560



